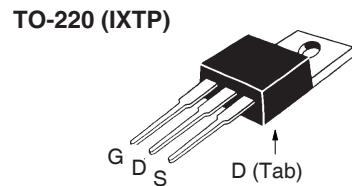
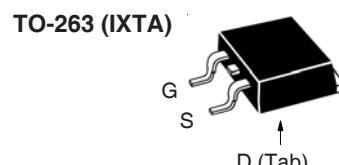
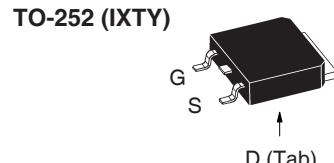
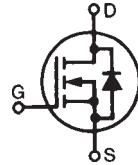


Polar™
Power MOSFET

IXTY1R4N100P
IXTA1R4N100P
IXTP1R4N100P

V_{DSS} = 1000V
I_{D25} = 1.4A
R_{DS(on)} ≤ 11.8Ω

N-Channel Enhancement Mode
Avalanche Rated



G = Gate D = Drain
S = Source Tab = Drain

Symbol	Test Conditions	Maximum Ratings	
V _{DSS}	T _J = 25°C to 150°C	1000	V
V _{DGR}	T _J = 25°C to 150°C, R _{GS} = 1MΩ	1000	V
V _{GSS}	Continuous	±20	V
V _{GSM}	Transient	±30	V
I _{D25}	T _C = 25°C	1.4	A
I _{DM}	T _C = 25°C, Pulse Width Limited by T _{JM}	3.0	A
I _A	T _C = 25°C	1.4	A
E _{AS}	T _C = 25°C	100	mJ
dv/dt	I _S ≤ I _{DM} , V _{DD} ≤ V _{DSS} , T _J ≤ 150°C	10	V/ns
P _D	T _C = 25°C	63	W
T _J		-55 ... +150	°C
T _{JM}		150	°C
T _{stg}		-55 ... +150	°C
T _L	Maximum Lead Temperature for Soldering	300	°C
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C
F _c M _d	Mounting Force (TO-263) Mounting Torque (TO-220)	10.65 / 2.2 .. 14.6 1.13 / 10	N/lb Nm/lb.in
Weight	TO-252 TO-263 TO-220	0.35 2.50 3.00	g

Symbol	Test Conditions (T _J = 25°C, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
BV _{DSS}	V _{GS} = 0V, I _D = 250μA	1000		V
V _{GS(th)}	V _{DS} = V _{GS} , I _D = 50μA	2.5		4.5 V
I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±50 nA
I _{DSS}	V _{DS} = V _{DSS} , V _{GS} = 0V T _J = 125°C			5 μA 150 μA
R _{DS(on)}	V _{GS} = 10V, I _D = 0.5 • I _{D25} , Note 1			11.8 Ω

Features

- International Standard Packages
- Low Q_G
- Avalanche Rated
- Low Package Inductance
- Fast Intrinsic Rectifier

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

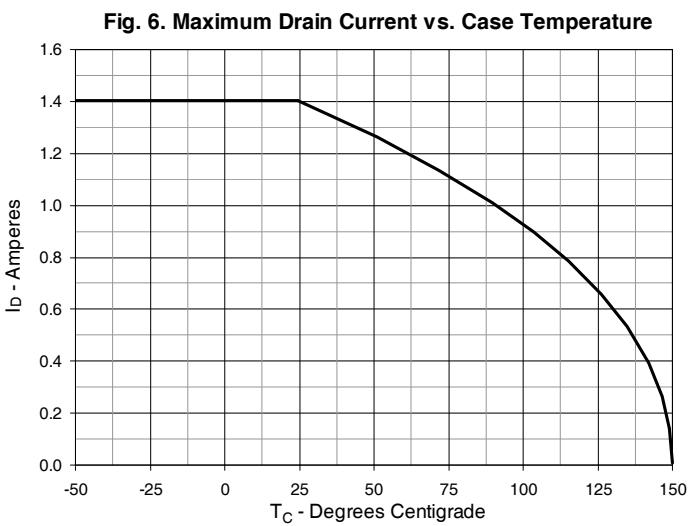
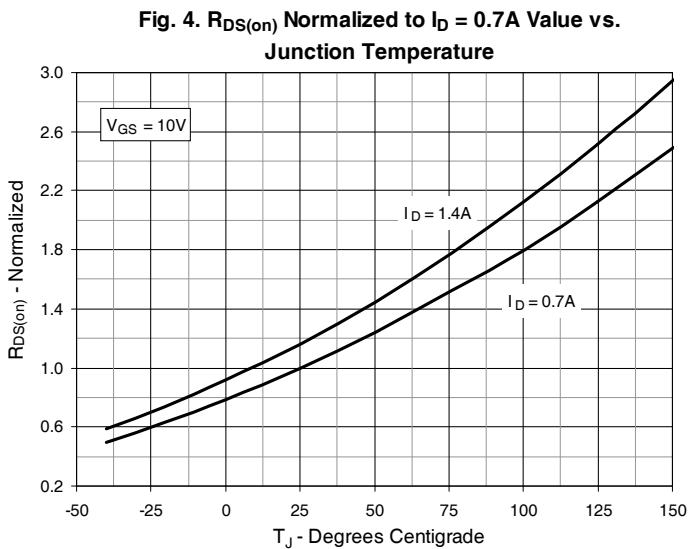
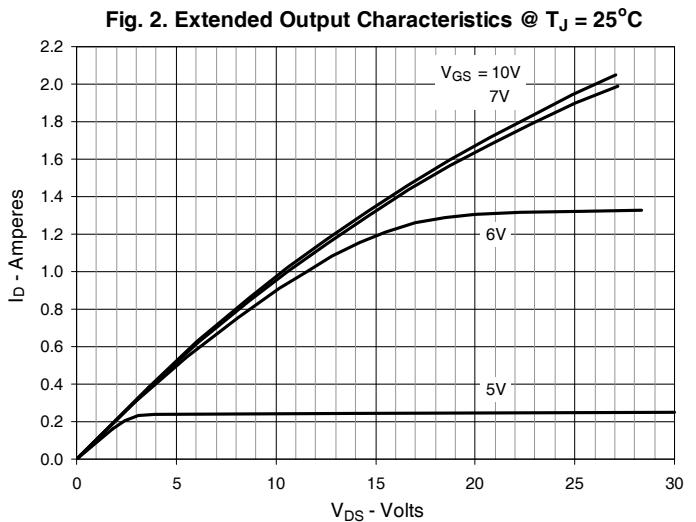
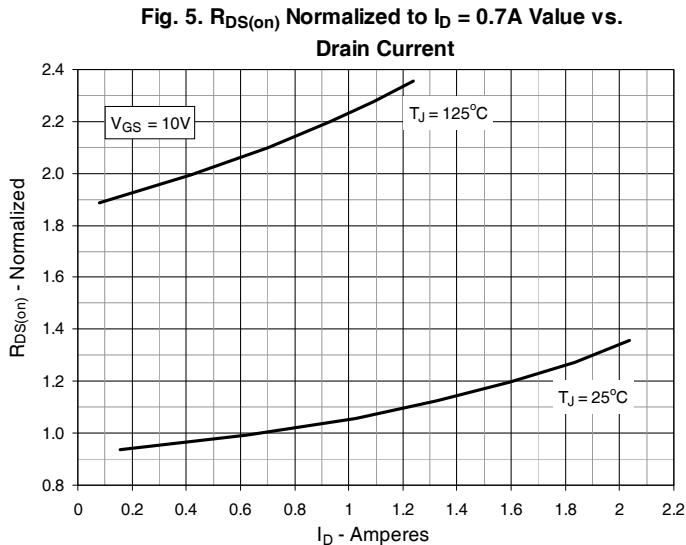
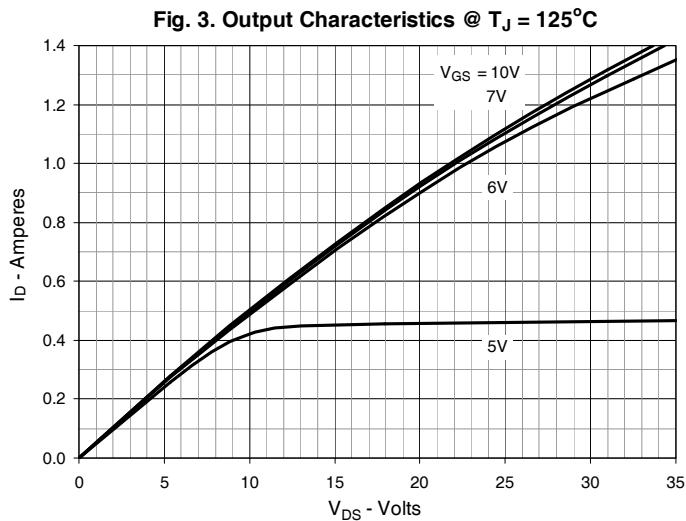
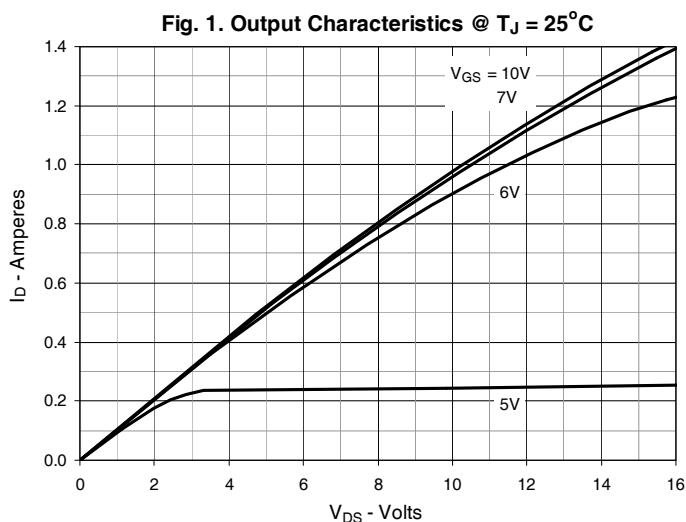
- DC-DC Converters
- Switch-Mode and Resonant-Mode Power Supplies
- AC and DC Motor Drives
- Lasers Drivers
- Robotics and Servo Controls

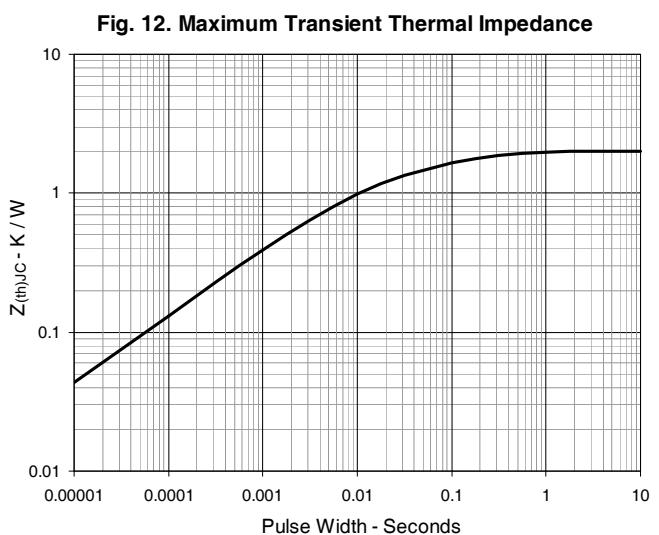
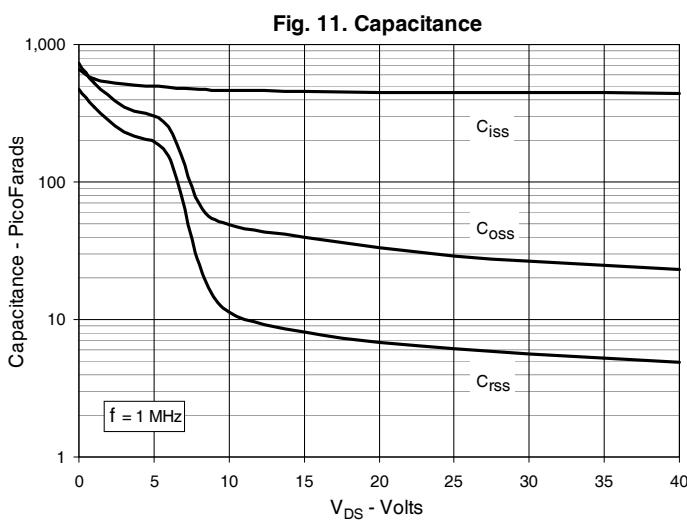
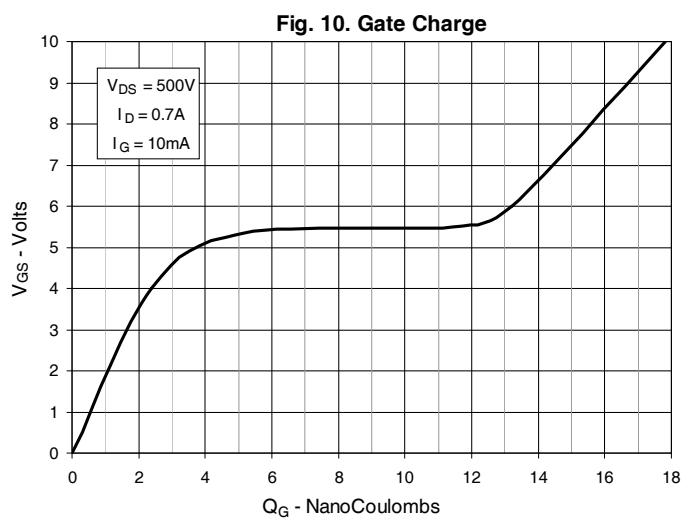
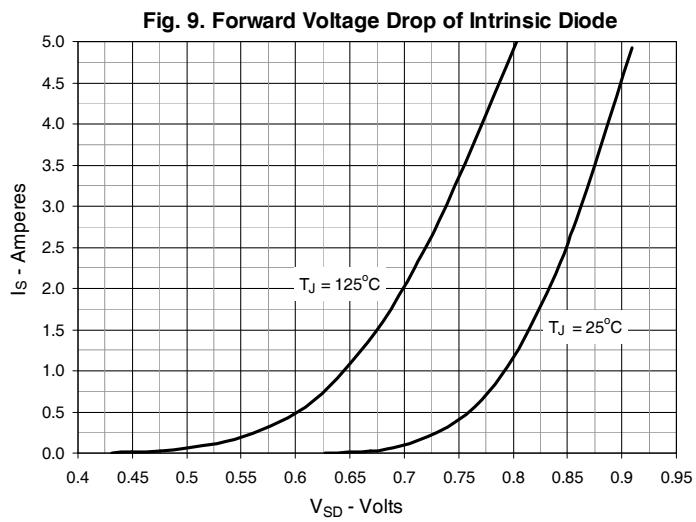
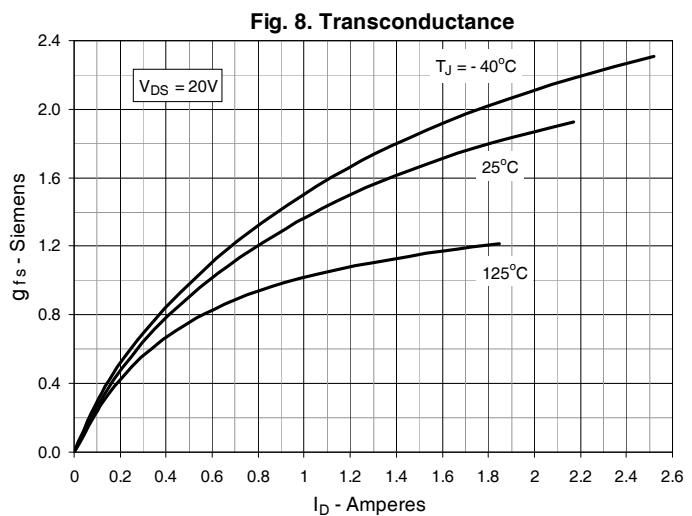
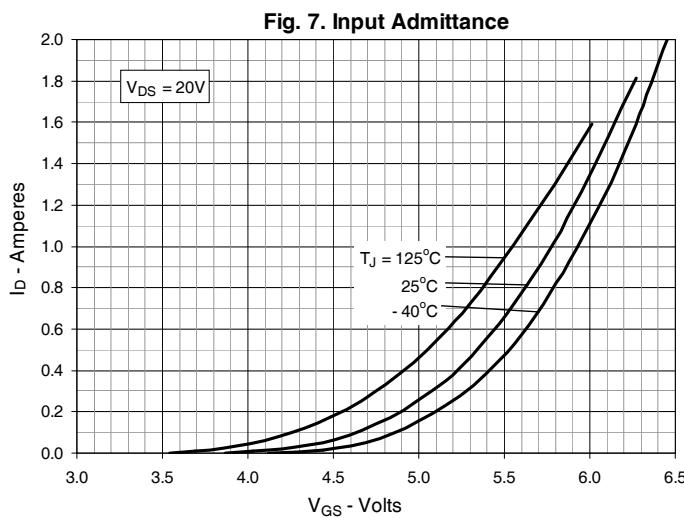
Symbol	Test Conditions (T _J = 25°C, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max
g_{fs}	V _{DS} = 20V, I _D = 0.5 • I _{D25} , Note 1	0.70	1.10	S
C_{iss}	V _{GS} = 0V, V _{DS} = 25V, f = 1MHz	450	pF	
C_{oss}		27	pF	
C_{rss}		6	pF	
Q_{g(on)}	V _{GS} = 10V, V _{DS} = 0.5 • V _{DSS} , I _D = 0.5 • I _{D25}	17.8	nC	
Q_{gs}		2.8	nC	
Q_{gd}		9.9	nC	
t_{d(on)}	Resistive Switching Times V _{GS} = 10V, V _{DS} = 0.5 • V _{DSS} , I _D = 0.5 • I _{D25} R _G = 30Ω (External)	25	ns	
t_r		35	ns	
t_{d(off)}		65	ns	
t_f		28	ns	
R_{thJC}	TO-220		2.0 °C/W	
R_{thCS}		0.50	°C/W	

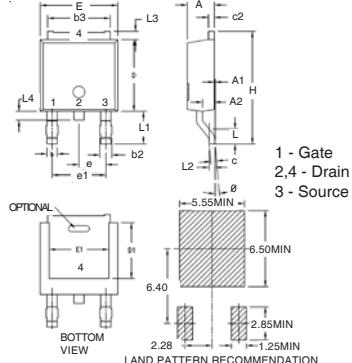
Source-Drain Diode

Symbol	Test Conditions (T _J = 25°C, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max
I_s	V _{GS} = 0V		1.4	A
I_{SM}	Repetitive, Pulse Width Limited by T _{JM}		4.2	A
V_{SD}	I _F = I _S , V _{GS} = 0V, Note 1		1.5	V
t_{rr}	I _F = 1.4A, -di/dt = 100A/μs, V _R = 100V	750		ns

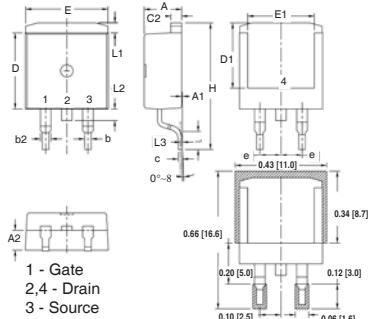
Note 1. Pulse test, t ≤ 300μs, duty cycle, d ≤ 2%.



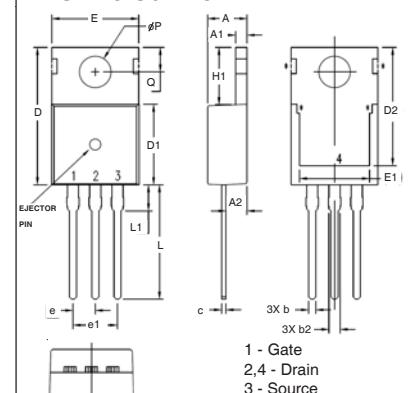


TO-252 AA Outline


SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.086	.094	2.19	2.38
A1	0	.005	0	.012
A2	.038	.046	0.97	1.17
b	.025	.035	0.64	0.89
b2	.030	.045	0.76	1.14
b3	.200	.215	5.08	5.46
c	.018	.024	0.46	0.61
c2	.018	.023	0.46	0.58
D	.235	.245	5.97	6.22
D1	.180	.205	4.57	5.21
E	.250	.265	6.35	6.73
E1	.170	.205	4.32	5.21
e	.090	BSC	2.28	BSC
e1	.180	BSC	4.57	BSC
H	.370	.410	9.40	10.42
L	.055	.070	1.40	1.78
L1	.100	.115	2.54	2.92
L2	.020	BSC	0.50	BSC
L3	.025	.040	0.64	1.02
L4	.025	.040	0.64	1.02
θ	0*	10*	0*	10*

TO-263 Outline


SYM	INCHES		MILLIMETER	
	MIN	MAX	MIN	MAX
A	.170	.185	4.30	4.70
A1	.000	.008	0.00	0.20
A2	.091	.098	2.30	2.50
b	.028	.035	0.70	0.90
b2	.046	.060	1.18	1.52
C	.018	.024	0.45	0.60
C2	.049	.060	1.25	1.52
D	.340	.370	8.63	9.40
D1	.300	.327	7.62	8.30
E	.380	.410	9.65	10.41
E1	.270	.330	6.86	8.38
e	.100	BSC	2.54	BSC
H	.580	.620	14.73	15.75
L	.075	.105	1.91	2.67
L1	.039	.060	1.00	1.52
L2	—	.070	—	1.77
L3	.010	BSC	0.254	BSC

TO-220 Outline


SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
b	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
c	.014	.026	0.35	0.65
D	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
e	.100	BSC	2.54	BSC
e1	.200	BSC	5.08	BSC
H1	.244	.268	6.20	6.80
L	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØP	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20



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